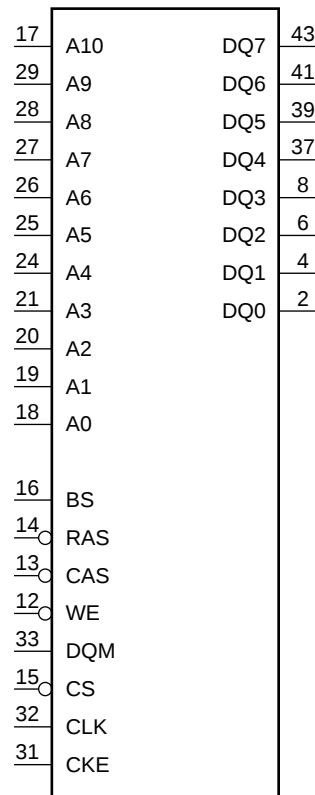
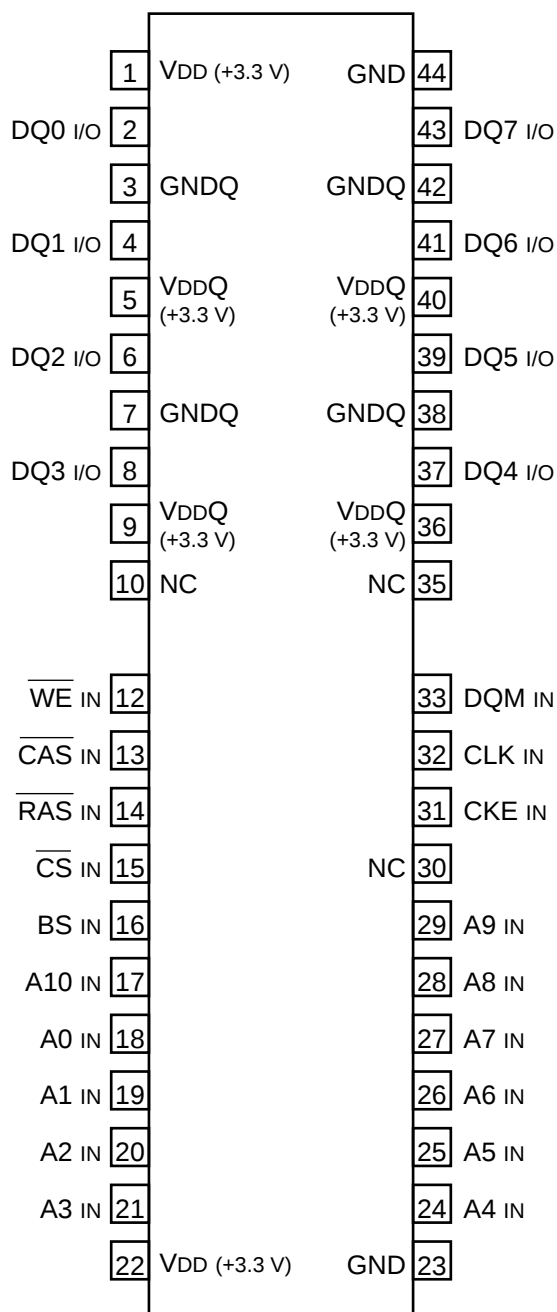

C-MOS 16 M (1,048,576x8x2)-BIT SYNCHRONOUS DYNAMIC RAM

- TOP VIEW -



INPUT

A0 - A10 ; ADDRESS
 BS ; BANK SELECT
 CAS ; COLUMN ADDRESS STROBE
 CKE ; CLOCK ENABLE
 CLK ; CLOCK
 CS ; CHIP SELECT
 DQM ; OUTPUT DISABLE/WRITE MASK
 RAS ; ROW ADDRESS STROBE
 WE ; WRITE ENABLE

INPUT/OUTPUT

DQ0 - DQ7 ; DATA

OTHER

GNDQ ; GROUND FOR DQ BUFFER
 VDDQ ; POWER SUPPLY FOR DQ BUFFER

